

# **MOSFET** – Power, Dual N-Channel, for 1-Cell Lithium-ion Battery Protection

12 V, 3.2 mΩ, 27 A

# **EFC8811R**

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

#### **Features**

- 2.5 V Drive
- 2 kV ESD HBM
- Common-Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

#### **Applications**

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

## **SPECIFICATIONS**

# ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>	12	\ \ \
Gate to Source Voltage	$V_{GSS}$	±8	V
Source Current (DC)	ls	27	Α
Source Current (Pulse) PW ≤[] 00 μs, Duty Cycle ≼[]%	I <sub>SP</sub>	100	Α
Total Dissipation Surface mounted on ceramic substrate (5000 mm <sup>2</sup> x 0.8 mm)	2.5	V	
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

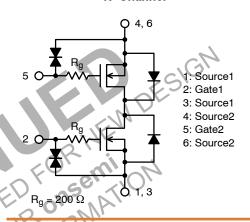
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient Surface mounted on ceramic substrate (5000 mm <sup>2</sup> x 0.8 mm)	$R_{ hetaJA}$	50	°C/W

V <sub>SSS</sub>	R <sub>SS(on)</sub> MAX	I <sub>S MAX</sub>
12 V	$3.2~\mathrm{m}\Omega$ @ $4.5~\mathrm{V}$	27 A
	3.2 mΩ @ 4.0 V	
	3.2 mΩ @ 3.8 V	
	4.4 mΩ @ 3.1 V	
	6.3 mΩ @ 2.5 V	

# ELECTRICAL CONNECTION N-Channel





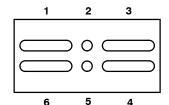
# MARKING DIAGRAM

CSP6, 1.77x3.54/ EFCP3517-6DGH-020 CASE 568AL o ML YMZZ

ML = Device CodeY = Year of Production

M = Month of Assembly OperationZZ = Assembly Lot Number

#### **PIN CONNECTIONS**



## ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V( <sub>BR</sub> ) <sub>SSS</sub>	I <sub>S</sub> = 1 mA, V <sub>GS</sub> = 0 V (Test Circuit 1)	12	=	-	V
Zero-Gate Voltage Source Current	I <sub>SSS</sub>	V <sub>SS</sub> = 10 V, V <sub>GS</sub> = 0 V (Test Circuit 1)	-	=	1	μΑ
Gate to Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±8 V, V <sub>SS</sub> = 0 V (Test Circuit 2)	-	=	±1	μΑ
Gate Threshold Voltage	V <sub>GS</sub> (th)	V <sub>SS</sub> = 6 V, I <sub>S</sub> = 1 mA (Test Circuit 3)	0.5	_	1.3	V
Forward Transconductance	9 <sub>FS</sub>	V <sub>SS</sub> = 6 V, I <sub>S</sub> = 3 A (Test Circuit 4)	-	19	-	S
Static Source to Source On-State	R <sub>SS(on)</sub> 1	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 4.5 V (Test Circuit 5)	1.8	2.3	3.2	mΩ
Resistance	R <sub>SS(on)</sub> 2	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 4.0 V (Test Circuit 5)	1.9	2.4	3.2	mΩ
	R <sub>SS(on)</sub> 3	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 3.8 V (Test Circuit 5)	2.0	2.6	3.2	mΩ
	R <sub>SS(on)</sub> 4	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 3.1 V (Test Circuit 5)	2.1	3.3	4.4	mΩ
	R <sub>SS(on)</sub> 5	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 2.5 V (Test Circuit 5)	2.7	4.0	6.3	mΩ
Turn-ON Delay Time	t <sub>d(on)</sub>	V <sub>SS</sub> = 6 V, V <sub>GS</sub> = 4.5 V, I <sub>S</sub> = 3 A		80	- ~	ns
Rise Time	t <sub>r</sub>	(Test Circuit 6)	-	570	~10,	ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			38,000	⊃. <sup>−</sup>	ns
Fall Time	t <sub>f</sub>			17,700	-	ns
Total Gate Charge	Qg	V <sub>SS</sub> = 6 V, V <sub>GS</sub> = 4.5 V, I <sub>S</sub> = 27 A (Test Circuit 7)	ME	100	-	nC
Forward Source to Source Voltage	$V_{F(S-S)}$	I <sub>S</sub> = 3 A, V <sub>GS</sub> = 0 V (Test Circuit 8)	-20/	0.75	1.2	V

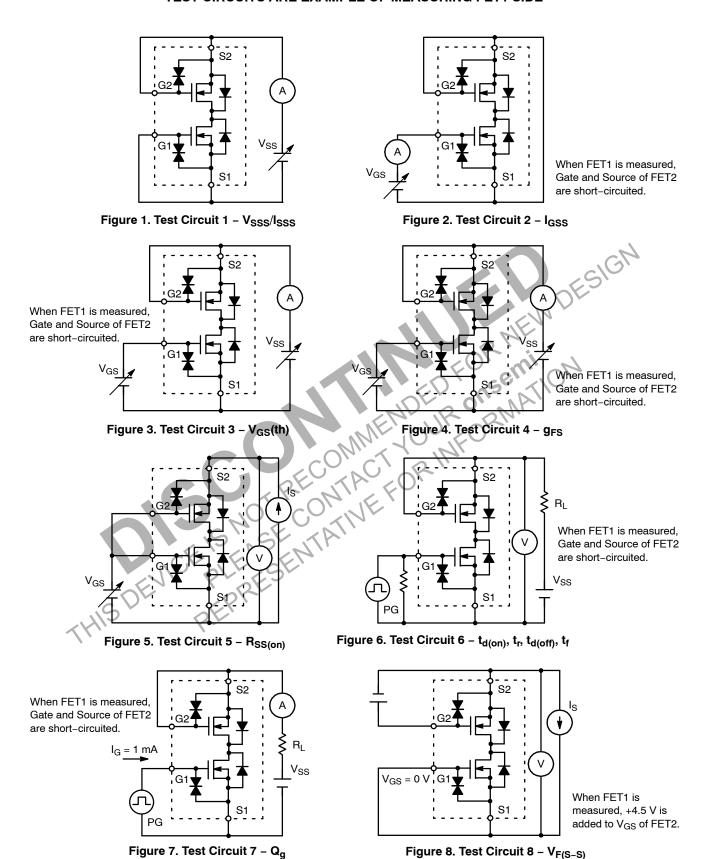
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# **ORDERING INFORMATION**

Device	Marking Package	Shipping (Qty / Packing) <sup>†</sup>
EFC8811R-TF	ML CSP6, 1.77 × 3.54 EFCP3517-6DGH-020 (Pb-Free / Halogen Free)	5,000 / Tape & Reel

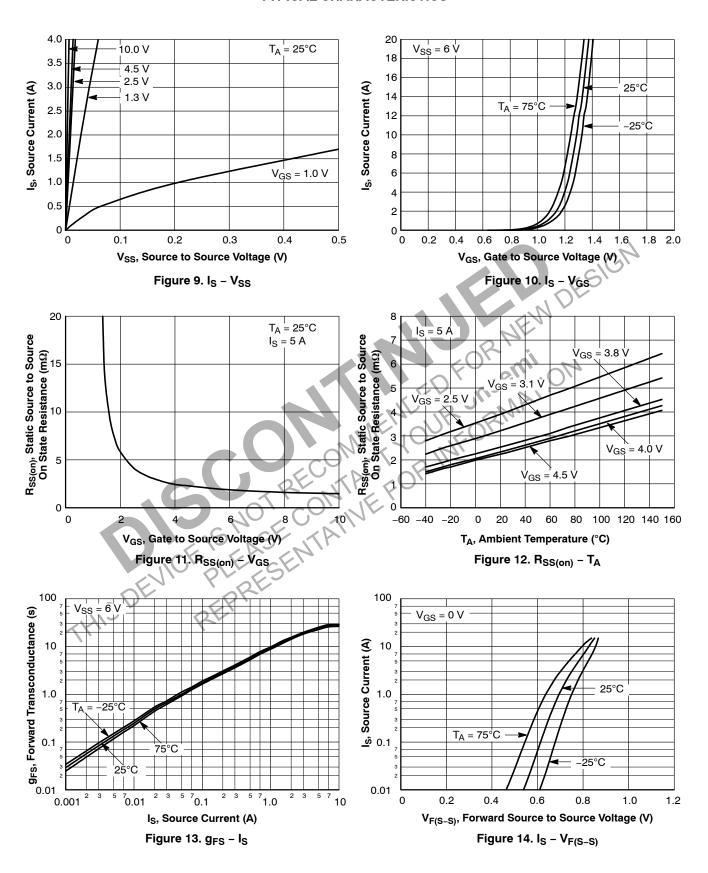
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### TEST CIRCUITS ARE EXAMPLE OF MEASURING FET1 SIDE



NOTE: When FET2 is measured, the position of FET1 and FET2 is switched.

#### **TYPICAL CHARACTERISTICS**



## TYPICAL CHARACTERISTICS (Continued)

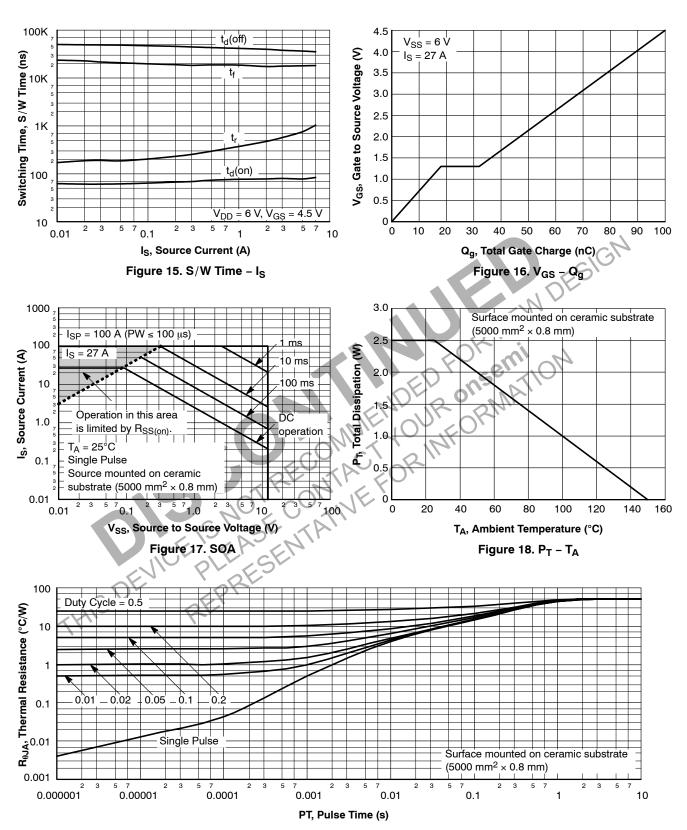


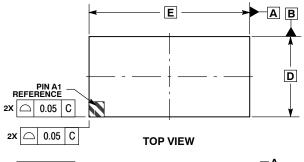
Figure 19.  $R_{\theta JA}$  – Pulse Time



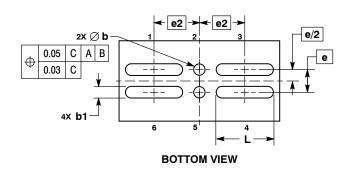


#### CSP6, 1.77x3.54 / EFCP3517-6DGH-020 CASE 568AL ISSUE O

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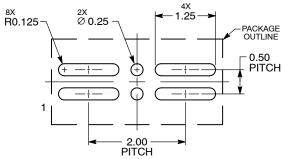


#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α		0.22	
b	0.22	0.28	
b1	0.22	0.28	
D	1.77 BSC		
E	3.54	BSC	
е	0.50 BSC 1.00 BSC		
e2			
L	1.22	1.28	

# RECOMMENDED SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:			PAGE 1 OF 1

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